NSN 5961-01-181-6676

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-181-6676 **Inclosure Material:** Metal **Overall Length:** 2.250 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 1.375 inches **Function For Which Designed:** Transient suppressor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 180.0 reverse voltage, instantaneous and 225.0 breakdown voltage, dc **Current Rating Per Characteristic:** 180.00 amperes peak pulse current **Power Rating Per Characteristic:** 10.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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